

## **Description**

The AO4480 uses advanced trench technology to provide excellent  $R_{DS(ON)}$ , low gate charge and operation with gate voltages as low as 4.5V. This device is suitable for use as a Battery protection or in other Switching application.

# S<sub>S</sub><sub>G</sub>

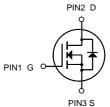
SOP-8

#### **General Features**

 $V_{DS} = 40V I_{D} = 9A$ 

 $R_{DS(ON)}$  < 16m $\Omega$  @ V<sub>GS</sub>=10V

 $R_{DS(ON)}$  < 24m $\Omega$  @  $V_{GS}$ =4.5V



# Application

Battery protection

Load switch

Uninterruptible power supply

N-Channel MOSFET

### **Package Marking and Ordering Information**

Product ID	Pack	Brand	Qty(PCS)
AO4480	SOP-8	HXY MOSFET	3000

# Absolute Maximum Ratings (Tc=25°C unless otherwise noted)

Symbol	Parameter	Limit	Unit
V <sub>D</sub> s	Drain-Source Voltage	40	V
Vgs	Gate-Source Voltage	±20	V
I <sub>D</sub>	Drain Current-Continuous	9	А
I <sub>D</sub> (70 °C)	Drain Current-Continuous(Tc=70°C)	6.4	Α
Ідм	Pulsed Drain Current	40	А
PD	Maximum Power Dissipation	2	W
T <sub>J</sub> ,T <sub>STG</sub>	Operating Junction and Storage Temperature Range	-55 To 150	°C

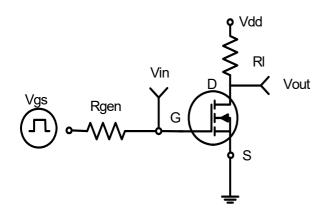


# **Electrical Characteristics Ta = 25°C**

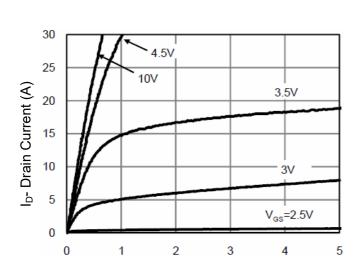
Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250μA	40	-	-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =40V,V <sub>GS</sub> =0V	-	-	1	μA
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±20V,V <sub>DS</sub> =0V		-	±100	nA
On Characteristics (Note 3)	·					
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS}=V_{GS},I_{D}=250\mu A$	1	1.5	2.0	V
Drain-Source On-State Resistance	Б	V <sub>GS</sub> =10V, I <sub>D</sub> =8A	-	12	16	mΩ
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =4.5V, I <sub>D</sub> =4A	-	19	24	mΩ
Forward Transconductance	<b>g</b> FS	V <sub>DS</sub> =5V,I <sub>D</sub> =8A	33	-	-	S
Dynamic Characteristics (Note4)				•		
Input Capacitance	C <sub>lss</sub>	\/ -20\/\/ -0\/	-	964	-	PF
Output Capacitance	C <sub>oss</sub>	$V_{DS}$ =20V, $V_{GS}$ =0V, F=1.0MHz	-	109	-	PF
Reverse Transfer Capacitance	C <sub>rss</sub>	F-1.UIVITZ	-	96	-	PF
Switching Characteristics (Note 4)						
Turn-on Delay Time	t <sub>d(on)</sub>		-	5.5	-	nS
Turn-on Rise Time	t <sub>r</sub>	$V_{DD}$ =20V, $R_L$ =2.5 $\Omega$	-	14	-	nS
Turn-Off Delay Time	t <sub>d(off)</sub>	$V_{GS}$ =10 $V$ , $R_{GEN}$ =3 $\Omega$	-	24	-	nS
Turn-Off Fall Time	t <sub>f</sub>		-	12	-	nS
Total Gate Charge	$Q_g$	\/ 00\/ L 0A	-	22.9	-	nC
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS}=20V,I_{D}=8A,$	-	3.5	-	nC
Gate-Drain Charge	Q <sub>gd</sub>	V <sub>GS</sub> =10V	-	5.3	-	nC
Drain-Source Diode Characteristics						
Diode Forward Voltage (Note 3)	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =9A	-	0.8	1.2	V



# **Typical Electrical and Thermal Characteristics**



**Figure 1:Switching Test Circuit** 



**Figure 3 Output Characteristics** 

Vds Drain-Source Voltage (V)

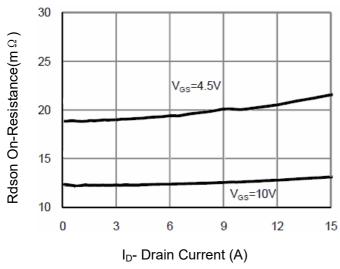


Figure 5 Drain-Source On-Resistance

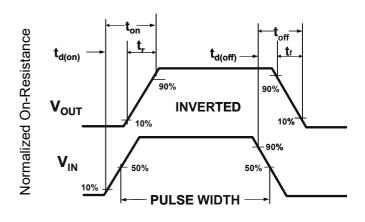
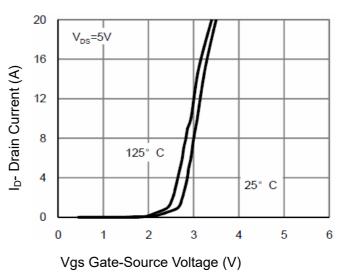


Figure 2:Switching Waveforms



**Figure 4 Transfer Characteristics** 

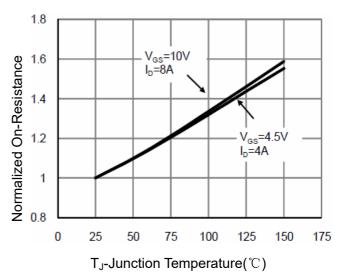
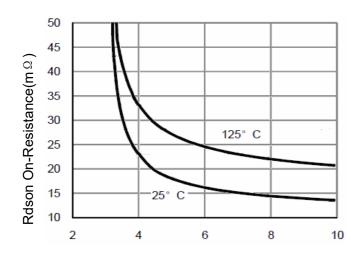


Figure 6 Drain-Source On-Resistance





Vgs Gate-Source Voltage (V)

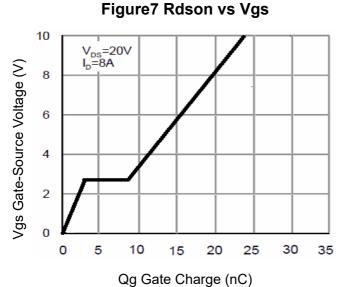


Figure 9 Gate Charge

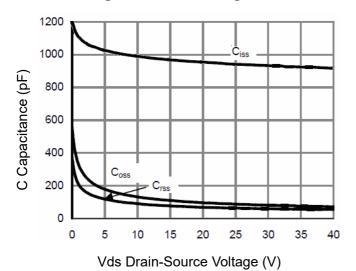
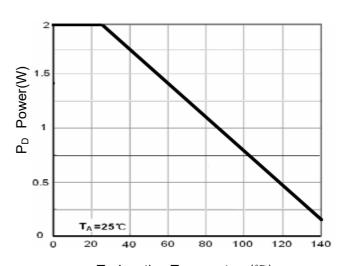


Figure 11 Capacitance vs Vds



T<sub>J</sub>-Junction Temperature(°C) Figure 8 Power Dissipation

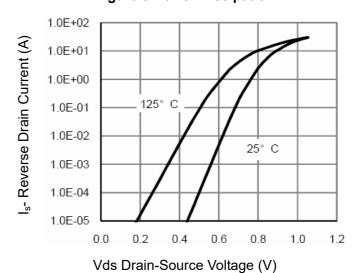
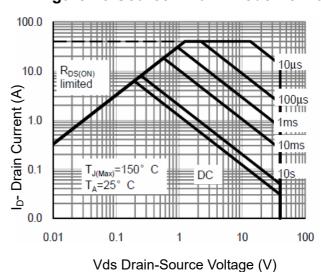


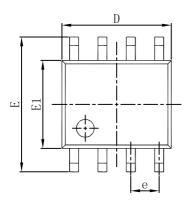
Figure 10 Source- Drain Diode Forward

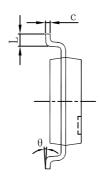


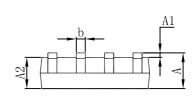
**Figure 12 Safe Operation Area** 



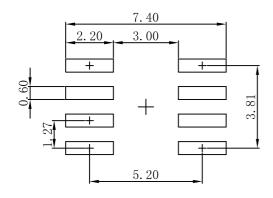
# **SOP-8 Package Outline Dimensions**







Symbol	Dimensions In Millimeters		Dimensions In Inches		
	Min	Max	Min	Max	
A	1.350	1.750	0.053	0.069	
A1	0.100	0.250	0.004	0.010	
A2	1.350	1.550	0.053	0.061	
b	0.330	0.510	0.013	0.020	
c	0.170	0.250	0.007	0.010	
D	4.800	5.000	0.189	0. 197	
e	1. 270 (	BSC)	0.050 (BSC)		
E	5.800	6. 200	0.228	0.244	
E1	3.800	4.000	0.150	0.157	
L	0.400	1.270	0.016	0.050	
θ	0°	8°	0°	8°	



- Note: 1.Controlling dimension:in millimeters.
- 2.General tolerance:± 0.05mm.
  3.The pad layout is for reference purposes only.



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